

# Scaling of the magnetic susceptibility and electrical resistivity in CeRhAl

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In this communication we report a discovery of a Fermi-liquid breakdown in CeRhAl that can be understood as complex effect of disorder. Our studies of polycrystalline CeRhAl sample suggest a weak magnetic ground state which could be related to the existence of a ferromagnetic clusters (ferromagnetic islands) in the paramagnetic sample. It has been reported [1] that CeRhAl adopts a different structure type than remaining compounds of the series RERhAl (RE is rare earth). While the other ReRhAl compounds crystallize in the orthorombic TiNiSi-type structure [1], CeRhAl has the orthorombic Pd<sub>2</sub>(MnPd)Ge<sub>2</sub>-type structure, which is a combination of orthorombic TiNiSi-type and hexagonal ZrNiAl-type structure, with the *c*-lattice parameter almost double of that in the TiNiSi-type RERhAl series. A comparison of the unit cell volume per formula unit in the RERhAl series shows a volume of CeRhAl smaller than the volume expected on the basis of lanthanide contraction [1], what suggests the mixed valence of Ce.

From the Ce 3d XPS spectra obtained for CeRhAl we estimated an occupation number of the *f*-shell (valence of Ce in CeRhAl) and the hybridization energy  $\Delta$  basing on the Gunnarsson-Schönhammer theoretical model [2]. The separation of the overlapping peaks was made on the basis of the Doniach-Šunjić theory [3]. Three final state contributions  $3d^9f^0$ ,

$3d^9f^1$ , and  $3d^9f^2$  are observed, which exhibit a spin-orbit splitting  $\Delta_{SO} = 18.6$  eV. The appearance of the  $3d^9f^0$  component in the 3d XPS spectrum of CeRhAl is clear evidence of the intermediate valence behavior of Ce. Based on the Gunnarsson-Schönhammer (GS) theoretical model, the intensity ratio  $I(f^0)/(I(f^0)+I(f^1)+I(f^2))$ , which should be directly related to the *f*-occupation probability in the final states, indicates an *f*-occupation number  $n_f=0.92$ . On the base of the GS model it is also possible to obtain the hybridization energy  $\Delta = \pi V_{fs}^2 \rho_{max}$ , which describes the hybridization part of the Anderson impurity Hamiltonian [4]. Here  $\rho_{max}$  is the maximum in the DOS and  $V_{fs}$  is the hybridization matrix element. It is possible to estimate  $\Delta$  from the ratio  $r=I(f^2)/(I(f^1)+I(f^2))$ , calculated as a function of  $\Delta$  in Ref. [2], when the peaks of the Ce 3d XPS spectra that overlap are separated. The intensity ratio  $r = 0.14$  gives for CeRhAl a crude estimate of a hybridization width  $\sim 70$  meV, which is twice smaller than  $\Delta$  value of CeRhSb or CeNiSn Kondo insulators [5]. The decreasing number of the conduction electrons (*n*-number) could be a reason which removes a hybridization gap in CeRhSb when Sb is replaced by Al (considering the fractional valence of Ce in CeRhAl, which is compared with that of CeRhSb).

The valence  $v>3$  of Ce in CeRhAl can not be, however, a main reason of existence of its curious structural properties in the RERhAl series. Ce usually exhibits a mixed valence behavior in the series of ternary intermetallic alloys, having the hexagonal (ZrNiAl-type) or orthorombic (TiNiSi-type) structure. CeRhSb is an example of a mixed valent Ce-based compound having a hybridization Kondo gap [6]. We therefore have investigated an electronic structure of CeRhAl, which usually decides about the structural properties of the compound. We also report an unusual temperature dependence of the magnetic susceptibility  $\chi(T)$  and electrical resistivity  $\rho(T)$  below 20 K. In CeRhAl the electrical resistivity  $\rho$  and magnetic susceptibility  $\chi$  have following scaling forms for  $T<20$  K:  $\rho(T) = \rho_0 + bT^{1.5}$  and  $\chi = \chi_0 + aT^{-1.6}$ , where *a* and *b* are positive. At the low temperatures  $\chi$  is strongly dependent on magnetic

field what is indicative of atomic disorder effect which can correspond to these power-law divergences in the T-dependencies of the physical properties at low temperatures.

In view of this observation we try to understand the power-law behavior in resistivity and susceptibility of CeRhAl. The temperature power-law exponents of  $\rho$  ( $\varepsilon=1.5$ ) and  $\chi$  ( $n=1.6$ ) obtained for CeRhAl are equal or close to the value  $3/2$  predicted by the spin-fluctuation theory for AFM-QCP in 3D (D being the spatial dimension) [7,8]. The influence of the weak magnetic phase on the measured properties as well as its significance for a correct theoretical explanation is, however, unclear.

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